



1 Amp To 2 Amp Standard Recovery Rectifiers

DESCRIPTION

This miniature, standard recovery rectifier diode series offers the user extreme reliability for high-reliability applications. These devices are available in the leaded A package configuration. Microsemi also offers numerous other rectifier products to meet higher and lower current ratings with various recovery time requirements including standard, fast and ultrafast device types in both through-hole and surface mount packages.

Important: For the latest information, visit our website http://www.microsemi.com.

FEATURES

- Miniature voidless hermetically sealed glass package.
- Continuous current rating of 2 amps.
- · Extremely robust construction.
- Internal "Category 1" metallurgical bonds.
- RoHS compliant versions available.

APPLICATIONS / BENEFITS

- Standard recovery 1 amp to 2 amp rectifier series with a V_{RWM} range from 100 to 1000 V.
- Surge current rating to 30 amps.
- Low thermal resistance.
- Controlled avalanche breakdown with peak reverse power capability.
- Inherently radiation hard as described in Microsemi MicroNote 050.

MAXIMUM RATINGS @ T_A= 25 °C unless otherwise specified

Parameters/Test Conditions			Symbol	Value	Unit	
Junction and Storage Temperature			T _J /T _{STG}	-65 to +175	°C	
Thermal Resistance Junction-to-Lead			R _{OJL}	See Derating Curves		
@ .375 inch lead length from body						
Working Peak Reverse Voltage:						
1 A	1.25 A	1.5 A	2 A			
UT236	UT249	UT251	UT261	V_{RWM}	100	V
UT234	UT242	UT252	UT262		200	
UT235	UT244	UT254	UT264		400	
UT237	UT245	UT255	UT265		500	
UT238	UT247	UT257	UT267		600	
UT361	UT362	UT258	UT268		800	
UT347	UT363	UT364	-		1000	
Forward Surge Current (Peak)	1 &	1.25 Am	p Series	I _{FSM}	20	Α
@ 8.3 ms		1.5 Am	p Series		25	
		2 Am	p Series		30	
Average Rectified Output Current		1 Amı	p Series	I _{O1}	1.0	Α
@ T _L = +25 °C		1.25 Am	p Series		1.25	
_		1.5 Am	p Series		1.5	
		2 Am	p Series		2.0	
Average Rectified Output-Current		1 Amı	p Series	I ₀₂	0.5	Α
@ T _A = +100 °C		1.25 Am			0.65	
			p Series		0.75	
		2 Am	p Series		1.0	
Solder Temperature @ 10 s				T _{SP}	260	°C



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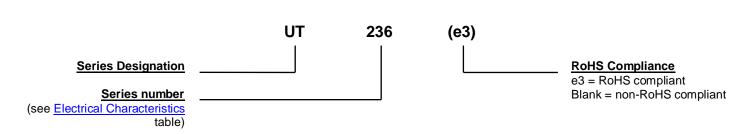
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MECHANICAL and PACKAGING

- CASE: Hermetically sealed voidless hard glass with tungsten slugs.
- TERMINALS: Tin/lead or RoHS compliant matte/tin over nickel plated over copper.
- MARKING: Orange band indicates "UT", part number printed on body.
- · POLARITY: Indicated by orange band.
- TAPE & REEL option: Standard per EIA-296. Consult factory for quantities.
- WEIGHT: Approximately 0.26 grams.
- See package dimensions on last page.

PART NOMENCLATURE



SYMBOLS & DEFINITIONS				
Symbol	Definition			
I _F	Forward Current: The forward current dc value, no alternating component.			
I _{FSM}	Maximum Forward Surge Current: The forward current, surge peak or rated forward surge current.			
Io	Average Rectified Output Current: Output current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.			
T _J	Junction Temperature: The temperature of a semiconductor junction.			
V _F	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.			
V_{RWM}	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range.			



ELECTRICAL CHARACTERISTICS @ 25 °C unless otherwise noted

	WORKING PEAK REVERSE VOLTAGE V _{RWM}	MAXIMUM FORWARD VOLTAGE DROP	MAXIMUM CURF @ V	RENT	
TVDE			μΑ		
TYPE	Volts	Volts	25 °C 100 °C		
UT261	100		2	75	
UT262	200				
UT264	400	4) / @ 000 4			
UT265	500	1 V @ 900 mA			
UT267	600				
UT268	800				
UT251	100	1 V @ 750 mA	2	75	
UT252	200				
UT254	400				
UT255	500				
UT257	600				
UT258	800				
UT364	1000				
UT249	100		2	75	
UT242	200				
UT244	400				
UT245	500	1 V @ 500 mA			
UT247	600				
UT362	800				
UT363	1000				
UT236	100	1 V @ 400 mA	2	75	
UT234	200				
UT235	400				
UT237	500				
UT238	600				
UT361	800				
UT347	1000				



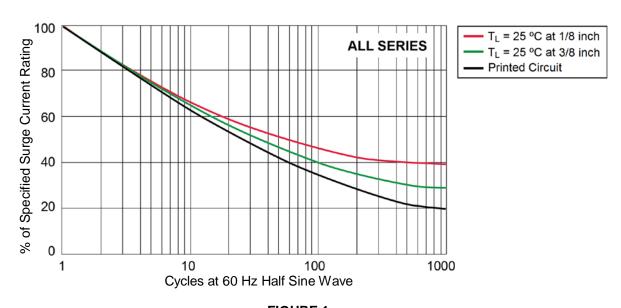


FIGURE 1
Allowable Forward Surge Current vs Number of Cycles

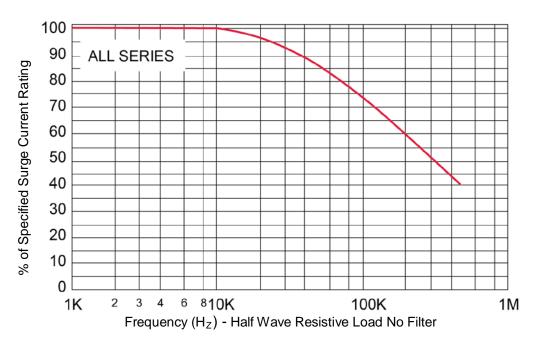


FIGURE 2
Efficiency vs Frequency at Rated Current (Sine Wave)



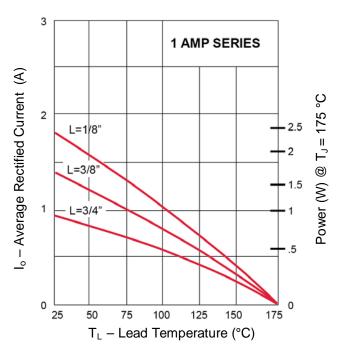


FIGURE 3

Maximum Current vs Lead Temperature

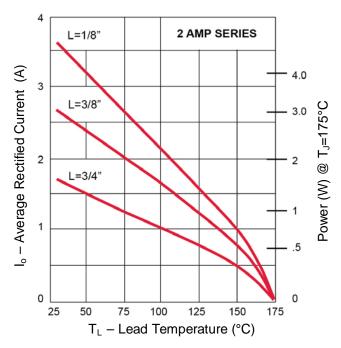


FIGURE 4
Maximum Current vs Lead Temperature



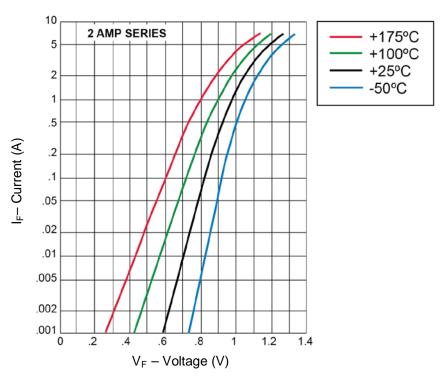


FIGURE 5
Typical Forward Current vs Forward Voltage

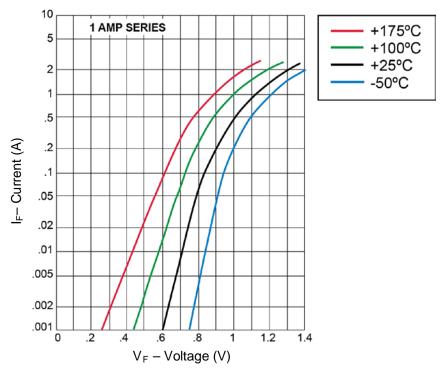


FIGURE 6
Typical Forward Current vs Forward Voltage



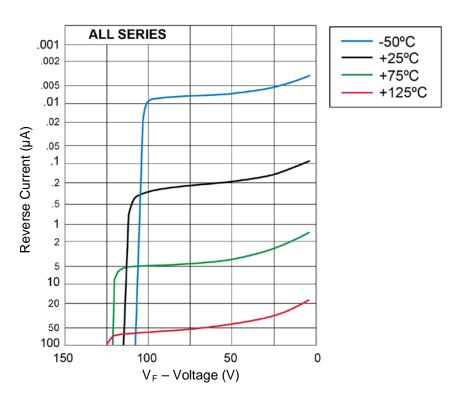
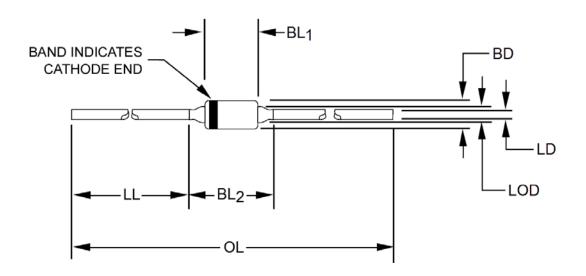


FIGURE 7

Typical Leakage Current vs Working Peak Reverse Voltage (V_{RWM})



PACKAGE DIMENSIONS



NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- Dimension BL₂ shall include the entire body including slugs and sections of the lead over which the diameter is uncontrolled. This uncontrolled area is defined as the zone between the edge of the diode body and extending 0.050 inch (1.27 mm) onto the leads.
- 4. Dimension BD shall be measured at the largest diameter.
- 5. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

Ltr INCHES		HES	MILLIM	Notes	
	Min	Max	Min	Max	
BD	0.065	0.085	1.65	2.16	4
BL ₁	0.155 TYP		3.9		
BL_2	0.125	0.250	3.18	6.35	3
LD	0.027	0.032	0.69	0.81	3
LL	0.700	1.30	17.78	33.02	
LOD	0.055 TYP		1.4		
OL	1.625	-	41.3	-	